Total No.	of Questions : 4] SEAT No. :							
PB291	[Total No. of Pages : 2							
1 02/1	[6270] 80							
B.E. (Electronics & Telecommunication Engineering) (Insem)								
FIBER OPTIC COMMUNICATION								
(2019 Pattern) (Semester-VIII) (404190)								
Time: 1 H	[Max. Marks: 30							
Instructions to the cardidates:								
	Answer Q.1 or Q.2, Q.3 or Q.4 from following questions.							
	2) Neat diagrams must be drawn wherever necessary.							
	3) Figures to the right indicate full marks. 4) Assume suitable data, if necessary.							
_	Assume sumble and, if necessary.							
Q1) a)	A step index fiber has a relative refractive index difference of 1.3% & a							
core refractive index of 1.5. The core diameter is 100 µm and operating								
	wavelength is 850nm. Assuming fiber is kept in air, calculate numerical							
b)	aperture of fiber, acceptance angle and critical angle. [6]							
b)	Compare single mode and multimode fibers. [4]							
6)	c) Draw and explain optical fiber communication system showing all the							
	key elements. Enlist the advantages of optical fibers as a communication media. [5]							
	OR							
Q2) a)	Explain intramodal dispersion, intermodal dispersion and overall fiber							
Q2) u)	dispersion in optical fibers. [4]							
b)	A multimode graded index fiber exhibits total pulse broadening of							
0)	0.1 μsec over a distance of 15km. Calculate. [6]							
	i) Maximum possible bandwidth on the link							
	ii) The pulse dispersion per unit length							
	iii) The bandwidth-length product for the fiber							
c)	Describe the following losses in optical fiber. [5]							
- /	i) Absorption							
	ii) Attenuation							
	iii) Scattering							
	m) Statering							

<i>Q3</i>)	a)	Explain the following terms for semiconductor laser diodes with neat				
		diag	ram			[5]
		i)	Absorption			
		ii)	Spontaneous Emissi	ion		
		iii)	Stimulate Emission	×.		
	b)	Exp	ms. State its ad-			
		vant	tages and disadvantag	ges.		[4]
	c)	A do	ouble heterojunction I	emitting at a pea	k wavelength of	
		1310 nm has radiative and non-radiative recombination times of 30				
		100	ns respectively. The d	lrive current is	s 40 mA Determi	ne
		i)	Bulk recombination 1	lifetime		
		ii)	The internal quantum	n efficiency		
		Sii)	Internal power level	2	S.YO.	[6]
				OR	*	
Q4)	a)	Exp	lain external quantum	efficiency an	d the external po	wer generated in
		the I	LED with necessary	quations.		[6]
	b)	Dist	inguish direct and Inc	direct band-ga	ap semiconductor	r materials. Also
		state	e the major requireme	ents of good o	ptical sources.	[6]
	c)	Calc	culate the emission w	avelength in	nm of the light	emitted using a
		sem	iconductor material w	ith energy ba	nd-gap of 3eV	[3]
			iconductor material w	• •		, William Control of the Control of
					130 of 18	emitted using a [3]
				(
					80.7	
				· V	7	

[6270]-80